

LD2980ABxx LD2980Cxx

Ultra low drop voltage regulators compatible with low ESR inhibit output capacitors

Features

- Stable with low ESR ceramic capacitors
- Ultra low dropout voltage (0.12 V typ. at 50 mA load, 7 mV typ. at 1 mA load)
- Very low quiescent current (80 µA typ. at no load in on mode; max 1 µA in off mode)
- Guaranteed output current up to 50 mA
- Logic-controlled electronic shutdown
- Output voltage of 1.8; 2.5; 3.0; 3.3; 3.6; 5.0 V
- Internal current and thermal limit
- ± 0.5% Tolerance output voltage available (A version)
- Output low noise voltage 160 µVRMS
- Temperature range: -40 to 125 °C
- Smallest package SOT23-5L and SOT-89
- Fast dynamic response to line and load changes

Description

The low drop-voltage and the ultra low quiescent current make them suitable for low noise, low power applications and in battery powered



SOT23-5L	SOT-89

systems. The quiescent current in sleep mode is less than 1 μ A when the INHIBIT pin is pulled low. A shutdown logic control function is available on pin n° 3 (TTL compatible). This means that when the device is used as local regulator, it is possible to put a part of the board in standby, decreasing the total power consumption. The LD2980 is designed to work with low ESR ceramic capacitors. Typical applications are cellular phone, laptop computer, personal digital assistant (PDA), personal stereo, camcorder and camera.

Order codes						
AB Version		AB Version C Version		Output voltage		
SOT23-5L	SOT-89	SOT23-5L SOT-89		Output voltage		
		LD2980CM18TR	LD2980CU18TR	1.8 V		
LD2980ABM25TR	LD2980ABU25TR (1)	LD2980CM25TR	LD2980CU25TR (1)	2.5 V		
LD2980ABM30TR	LD2980ABU30TR (1)	LD2980CM30TR (1)	LD2980CU30TR (1)	3.0 V		
LD2980ABM33TR	LD2980ABU33TR	LD2980CM33TR		3.3 V		
LD2980ABM36TR	LD2980ABU36TR (1)	LD2980CM36TR	LD2980CU36TR (1)	3.6 V		
LD2980ABM50TR	LD2980ABU50TR	LD2980CM50TR	LD2980CU50TR	5.0 V		

1. Available on request.

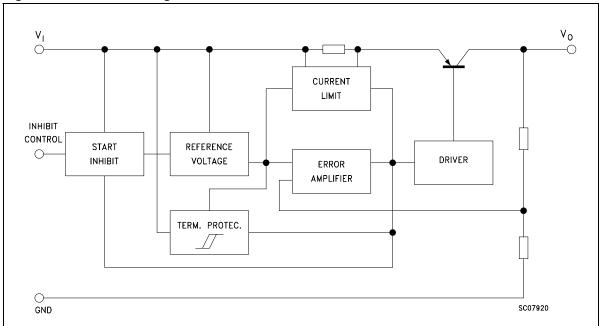
February 2008

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1 Diagram





2 Pin configuration





Table 2.Pin description

Pin n° SOT23-5L	Pin n° SOT-89	Symbol	Name and Function
1	3	V _{IN}	Input port
2	2	GND	Ground pin
3		INHIBIT	Control switch ON/OFF. Inhibit is not internally pulled-up; it cannot be left floating. Disable the device when connected to GND or to a positive voltage less than 0.18 V
4		NC	Not connected
5	1	V _{OUT}	Output port

Table 3. Thermal data

Symbol	Symbol Parameter		SOT-89	Unit
R _{thJC}	Thermal resistance junction-case	81	15	°C/W
R _{thJA}	Thermal resistance junction-ambient	255	110	°C/W

3 Maximum ratings

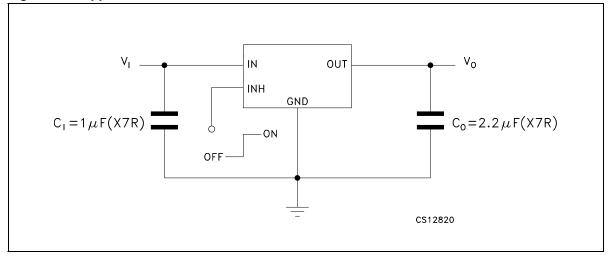
Symbol	Parameter	Value	Unit
VI	VI DC input voltage		V
V _{INH}	INHIBIT input voltage	-0.3 to 16	V
Ι _Ο	Output current	Internally limited	
PD	Power dissipation	Internally limited	
T _{STG}	Storage temperature range	-55 to 150	°C
T _{OP}	Operating junction temperature range	-40 to 125	°C

Table 4. Absolute maximum ratings

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

4 Typical application

Figure 3. Application circuit



Note: Inhibit pin is not internally pulled-up then it must not be left floating. Disable the device when connected to GND or to a positive voltage less than 0.18 V.

Electrical characteristics 5

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{OP}	Operating input voltage		2.5		16	V
		I _O = 1 mA	2.487	2.5	2.513	
Vo	Output voltage	I _O = 1 to 50 mA	2.481		2.519	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	2.437		2.562	
		I _O = 1 mA	2.835	2.85	2.864	
Vo	Output voltage	I _O = 1 to 50 mA	2.828		2.871	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	2.779		2.921	
		I _O = 1 mA	2.985	3	3.015	
Vo	Output voltage	I _O = 1 to 50 mA	2.978		3.023	v
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	2.925		3.075	
		I _O = 1 mA	3.184	3.2	3.216	
Vo	Output voltage	I _O = 1 to 50 mA	3.176		3.224	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	3.12		3.28	
		I _O = 1 mA	3.284	3.3	3.317	
Vo	Output voltage	I _O = 1 to 50 mA	3.275		3.325	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	3.217		3.383	
V _O Oi	Output voltage	I _O = 1 mA	3.582	3.6	3.618	v
		I _O = 1 to 50 mA	3.573		3.627	
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$				
		I _O = 1 mA	3.781	3.8	3.819	
Vo	Output voltage	I _O = 1 to 50 mA	3.772		3.829	v
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	3.705		3.895	
		I _O = 1 mA	3.98	4	4.02	
Vo	Output voltage	I _O = 1 to 50 mA	3.97		4.03	v
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	3.9		4.1	
		I _O = 1 mA	4.677	4.7	4.724	
Vo	Output voltage	I _O = 1 to 50 mA	4.665		4.735	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	4.582		4.818	
		I _O = 1 mA	4.826	4.85	4.874	
Vo	Output voltage	I _O = 1 to 50 mA	4.814		4.886	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to 125°C	4.729	İ	4.971	
		I _O = 1 mA	4.975	5	5.025	
Vo	Output voltage	I _O = 1 to 50 mA	4.963	İ	5.038	v
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to 125°C	4.875		5.125	
A) /	Line regulation	V _{O(NOM)} + 1 < V _{IN} < 16 V, I _O = 1 mA		0.003	0.014	0/ /
ΔV_O	Line regulation	T _J = -40 to 125°C		1	0.032	%/V

Electrical characteristics for LD2980AB (T₁ = 25 °C, V₁ = V_{O(NOM)} +1 V, C₁ = 1 μ F(X7R), Table 5.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
		I _O = 0		80	100	
		$I_{O} = 0, T_{J} = -40$ to $125^{\circ}C$			150	
		I _O = 1 mA		100	150	
	Quiescent current	$I_{O} = 1 \text{ mA}, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$			200	
	ON MODE	I _O = 10 mA		175	250	
Ι _Q		$I_{O} = 10 \text{ mA}, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$			450	μA
		I _O = 50 mA		500	700	
	OFF MODE	$I_{O} = 50 \text{ mA}, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$			1200	
		V _{INH} < 0.18 V		0		-
		$V_{\rm INH}$ < 0.18 V, $T_{\rm J}$ = -40 to 125°C			1	
	Dropout voltage (<i>Note 1</i>)	I _O = 0		1	3	mV
		$I_{O} = 0, T_{J} = -40$ to 125°C			5	
		I _O = 1mA		7	10	
V		$I_{O} = 1$ mA, $T_{J} = -40$ to 125° C			15	
V _{DROP}		I _O = 10mA		40	60	
		$I_{O} = 10$ mA, $T_{J} = -40$ to 125° C			90	
		I _O = 50mA		120	150	
		$I_{O} = 50$ mA, $T_{J} = -40$ to 125° C			225	
I _{SC}	Short circuit current	R _L = 0		150		mA
SVR	Supply voltage rejection	$C_{O} = 10\mu$ F, f = 1kHz		63		dB
V _{INH}	Inhibit input logic low	LOW = Output OFF, T_J = -40 to 125°C		0.8	0.18	V
V _{INL}	Inhibit input logic high	HIGH = Output ON, T_J = -40 to 125°C	1.6	1.3		V
I	Inhibit input current	$V_{INH} = 0V, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$		0	-1	Δ
I _{INH}		$V_{INH} = 5V, T_{J} = -40$ to 125°C		5	15	μA
e _N	Output noise voltage	$B_W = 300$ Hz to 50 kHz, $C_O = 10\mu F$		160		μV_{RMS}
T _{SHDN}	Thermal shutdown			170		°C

Table 5.	Electrical characteristics for LD2980AB (continued) ($T_J = 25 \text{ °C}, V_I = V_{O(NOM)} + 1 \text{ V}, C_I = V_{O(NOM$
	1 μ F(X7R), C _O = 2.2 μ F (X7R), I _O = 1 mA, V _{INH} = 2 V, unless otherwise specified).

Note: 1 For $V_O < 2.5$ V dropout voltage can be calculated according to the minimum input voltage in full temperature range.

Table 6.	Electrical characteristics for LD2980C ($T_J = 25 \text{ °C}$, $V_I = V_{O(NOM)} + 1 \text{ V}$, $C_I = 1 \mu F (X7R)$,
	$C_O = 2.2 \ \mu F (X7R)$, $I_O = 1 \ mA$, $V_{INH} = 2 \ V$, unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{OP}	Operating input voltage		2.5		16	V
		I _O = 1 mA	1.478	1.5	1.522	
Vo	Output voltage	I _O = 1 to 50 mA	1.470		1.530	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	1.445		1.555	
		I _O = 1 mA	1.782	1.8	1.818	
Vo	Output voltage	I _O = 1 to 50 mA	1.773		1.827	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	1.737		1.863	
		I _O = 1 mA	2.475	2.5	2.525	
Vo	Output voltage	$I_0 = 1$ to 50 mA	2.463		2.538	V
		$I_0 = 1$ to 50 mA, $T_J = -40$ to $125^{\circ}C$	2.412		2.587	
		I _O = 1 mA	2.822	2.85	2.879	
Vo	Output voltage	$I_0 = 1$ to 50 mA	2.807		2.893	V
		$I_0 = 1$ to 50 mA, $T_J = -40$ to $125^{\circ}C$	2.75		2.949	949
		I _O = 1 mA	2.97	3	3.03	
Vo	Output voltage	$I_0 = 1$ to 50 mA	2.955		3.045	V
		$I_0 = 1$ to 50 mA, $T_J = -40$ to $125^{\circ}C$	2.895		3.105	
		I _O = 1 mA	3.168	3.2	3.232	
Vo	Output voltage	$I_{O} = 1$ to 50 mA	3.152		3.248	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	3.088		3.312	
		I _O = 1 mA	3.267	3.3	3.333	
Vo	Output voltage	I _O = 1 to 50 mA	3.251		3.35	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	3.184		3.415	
		I _O = 1 mA	3.564	3.6	3.636	
Vo	Output voltage	$I_0 = 1$ to 50 mA	3.546		3.654	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	3.474		3.726	
		I _O = 1 mA	3.76	3.8	3.838	
Vo	Output voltage	$I_0 = 1$ to 50 mA	3.743		3.857	V
		$I_0 = 1$ to 50 mA, $T_J = -40$ to $125^{\circ}C$	3.667		3.933	
		I _O = 1 mA	3.96	4	4.04	
Vo	Output voltage	$I_0 = 1$ to 50 mA	3.94		4.06	V
		$I_0 = 1$ to 50 mA, $T_J = -40$ to $125^{\circ}C$	3.86		4.14	
		I _O = 1 mA	4.653	4.7	4.747	
Vo	Output voltage	I _O = 1 to 50 mA	4.630		4.771	V
		$I_0 = 1$ to 50 mA, $T_J = -40$ to $125^{\circ}C$	4.535		4.864	
		I _O = 1 mA	4.802	4.85	4.899	
Vo	Output voltage	I _O = 1 to 50 mA	4.777		4.923	V
		I _O = 1 to 50 mA, T _J = -40 to 125°C	4.68		5.02	

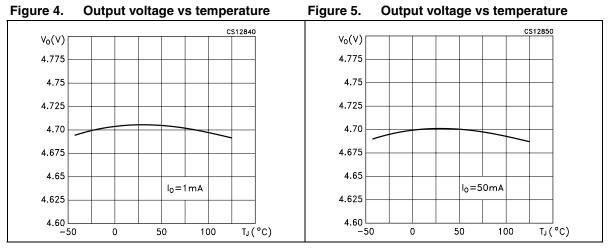
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
		I _O = 1 mA	4.95	5	5.05	
Vo	Output voltage	I _O = 1 to 50 mA	4.925		5.075	V
		$I_{O} = 1$ to 50 mA, $T_{J} = -40$ to $125^{\circ}C$	4.825		5.175	
ΔV _O	Line regulation	$V_{O(NOM)} + 1 < V_{IN} < 16 \text{ V}, I_O = 1 \text{ mA}$		0.003	0.014	%/V
Δvo		T _J = -40 to 125°C			0.032	32 ^{%/} V
		I _O = 0		80	100	
		$I_{O} = 0, T_{J} = -40$ to $125^{\circ}C$			150	
		I _O = 1 mA		100	150	
	Quiescent current	$I_{O} = 1 \text{ mA}, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$			200	
ON MODE	l _O = 10 mA		175	250		
Ι _Q		$I_{O} = 10 \text{ mA}, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$			450	μA
		l _O = 50 mA		500	700	
		$I_{O} = 50 \text{ mA}, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$			1200	
		V _{INH} < 0.18 V		0		
	OFF MODE	$V_{\rm INH}$ < 0.18 V, $T_{\rm J}$ = -40 to 125°C			1	
		I _O = 0		1	3	
		$I_{O} = 0, T_{J} = -40$ to $125^{\circ}C$			5	
		I _O = 1mA		7	10	
V	Dropout voltage (<i>Note 1</i>)	$I_{O} = 1$ mA, $T_{J} = -40$ to 125° C			15	mV
V _{DROP}		I _O = 10mA		40	60	1110
		I _O = 10mA, T _J = -40 to 125°C			90	
		I _O = 50mA		120	150	
		$I_{O} = 50$ mA, $T_{J} = -40$ to 125° C			225	
I _{SC}	Short circuit current	R _L = 0		150		mA
SVR	Supply voltage rejection	$C_{O} = 10\mu$ F, f = 1kHz		63		dB
V _{INH}	Inhibit input logic low	LOW = Output OFF, T_J = -40 to 125°C		0.8	0.18	V
V _{INL}	Inhibit input logic high	HIGH = Output ON, T_J = -40 to 125°C	1.6	1.3		V
I	Inhibit input current	$V_{INH} = 0V, T_{J} = -40 \text{ to } 125^{\circ}\text{C}$		0	-1	μF
I _{INH}		$V_{INH} = 5V, T_{J} = -40$ to $125^{\circ}C$		5	15	μι
e _N	Output noise voltage	$B_W = 300$ Hz to 50 kHz, $C_O = 10 \mu F$		160		μV _{RM}
T _{SHDN}	Thermal shutdown			170		°C

Table 6.Electrical characteristics for LD2980C (continued) ($T_J = 25 \text{ °C}$, $V_I = V_{O(NOM)} + 1 \text{ V}$, $C_I = 1 \mu F (X7R)$, $C_O = 2.2 \mu F (X7R)$, $I_O = 1 \text{ mA}$, $V_{INH} = 2 \text{ V}$, unless otherwise specified)

Note: 1 For $V_O < 2.5$ V dropout voltage can be calculated according to the minimum input voltage in full temperature range.

6 Typical performance characteristics

(T_J = 25 °C, V_I = V_{O(NOM)} +1 V, C_I = 1 μ F (X7R), C_O = 2.2 μ F (X7R), V_{INH} = 2 V, unless otherwise specified)







Quiescent current vs temperature

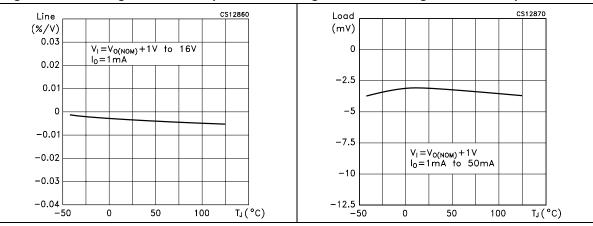


Figure 9.



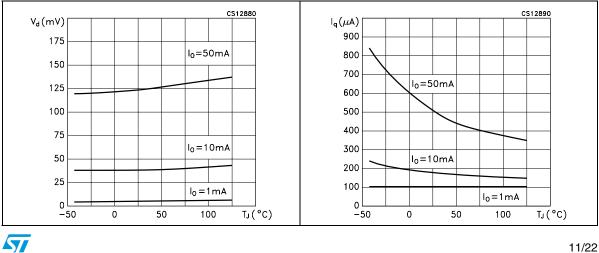


Figure 10. Quiescent current vs output

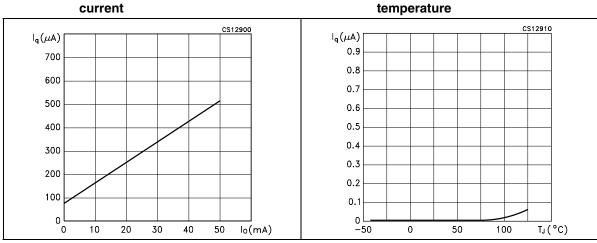
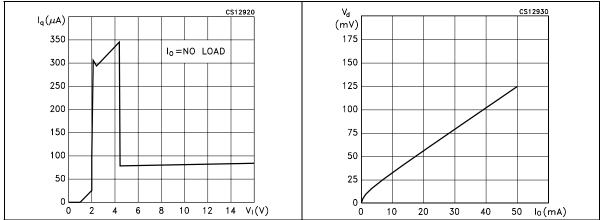
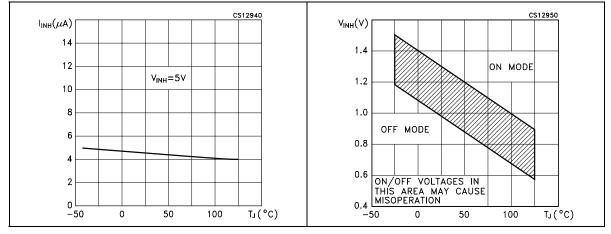


Figure 11. Off mode quiescent current vs temperature







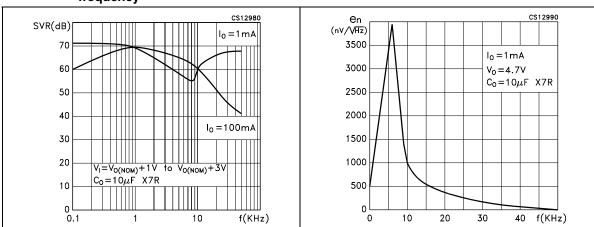


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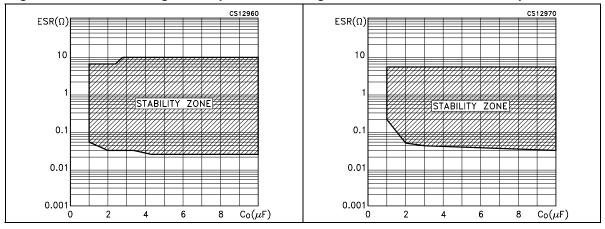


Figure 17. Noise voltage vs frequency

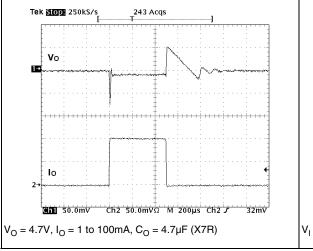
Typical performance characteristics



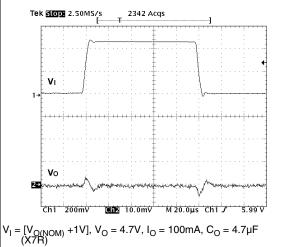












7 Application notes

7.1 External capacitors

Like any low-dropout regulator, the LD2980 requires external capacitors for regulator stability. This capacitor must be selected to meet the requirements of minimum capacitance and equivalent series resistance. We suggest to solder input and output capacitors as close as possible to the relative pins.

7.2 Input capacitor

An input capacitor whose value is 1 μ F is required with the LD2980 (amount of capacitance can be increased without limit). This capacitor must be located a distance of not more than 0.5" from the input pin of the device and returned to a clean analog ground. Any good quality ceramic, tantalum or film capacitors can be used for this capacitor.

7.3 Output capacitor

The LD2980 is designed specifically to work with ceramic output capacitors. It may also be possible to use Tantalum capacitors, but these are not as attractive for reasons of size and cost. By the way, the output capacitor must meet both the requirement for minimum amount of capacitance and ESR (equivalent series resistance) value. The *Figure 4* and *Figure 5* show the allowable ESR range as a function of the output capacitance. These curves represent the stability region over the full temperature and I_O range. Due to the different loop gain, the stability improves for higher output versions and so the suggested minimum output capacitor value, if low ESR ceramic type is used, is 1 μ F for output voltages equal or major than 3.8 V, 2.2 μ F for output voltages from 2.85 to 3.3 V, and 3.3 μ F for the other versions. However, if an output capacitor lower than the suggested one is used, it's possible to make stable the regulator adding a resistor in series to the capacitor (see *Figure 1 & Figure 2* to choose the right value according to the used version and keeping in account that the ESR of ceramic capacitors has been measured @ 100 kHz).

7.4 Important

The output capacitor must maintain its ESR in the stable region over the full operating temperature to assure stability. Also, capacitor tolerance and variation with temperature must be considered to assure the minimum amount of capacitance is provided at all times. This capacitor should be located not more than 0.5" from the output pin of the device and returned to a clean analog ground.

7.5 Inhibit input operation

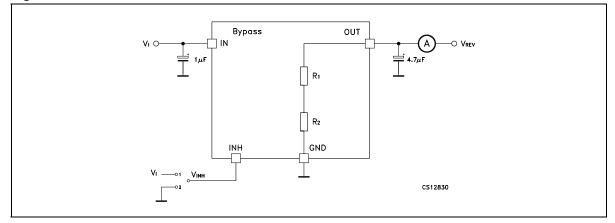
The inhibit pin can be used to turn OFF the regulator when pulled low, so drastically reducing the current consumption down to less than 1 μ A. When the inhibit feature is not used, this pin must be tied to V_I to keep the regulator output ON at all times. To assure proper operation, the signal source used to drive the inhibit pin must be able to swing above and below the specified thresholds listed in the electrical characteristics section under V_{IH} V_{IL}. Any slew rate can be used to drive the inhibit.

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7.6 Reverse current

The power transistor used in the LD2980 has not an inherent diode connected between the regulator input and output. If the output is forced above the input, no current will flow from the output to the input across the series pass transistor. When a V_{REV} voltage is applied on the output, the reverse current measured, according to the test circuit in *Figure 22*, flows to the GND across the two feedback resistors. This current typical value is 160 μ A. R₁ and R₂ resistors are implanted type; typical values are, respectively, 42.6 k Ω and 51.150 k Ω

Figure 22. Reverse current test circuit

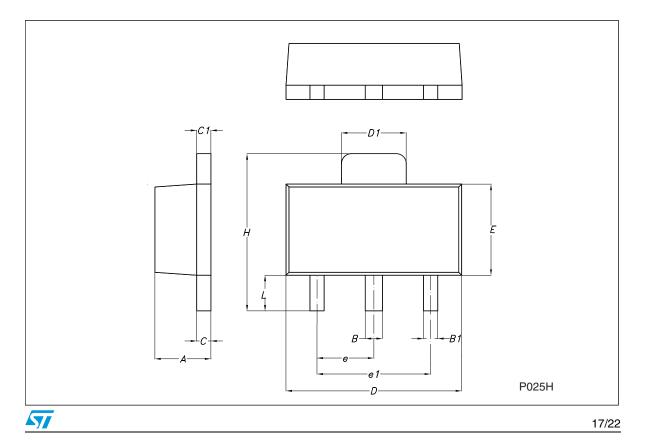


8 Package mechanical data

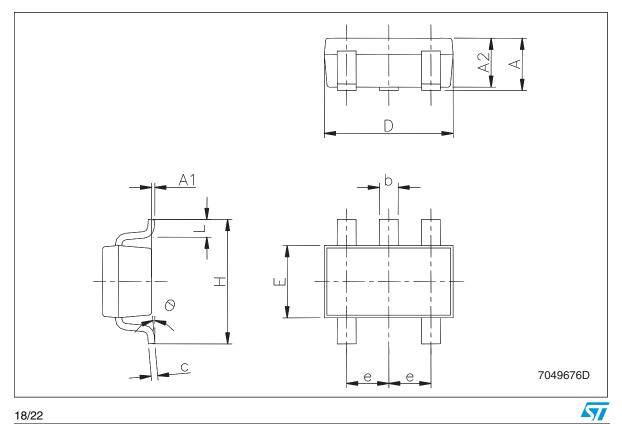
In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



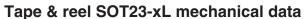
	SOT-89 mechanical data						
Dim.	mm.			mils.			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	1.4		1.6	55.1		63.0	
В	0.44		0.56	17.3		22.0	
B1	0.36		0.48	14.2		18.9	
С	0.35		0.44	13.8		17.3	
C1	0.35		0.44	13.8		17.3	
D	4.4		4.6	173.2		181.1	
D1	1.62		1.83	63.8		72.0	
E	2.29		2.6	90.2		102.4	
е	1.42		1.57	55.9		61.8	
e1	2.92		3.07	115.0		120.9	
Н	3.94		4.25	155.1		167.3	
L	0.89		1.2	35.0		47.2	

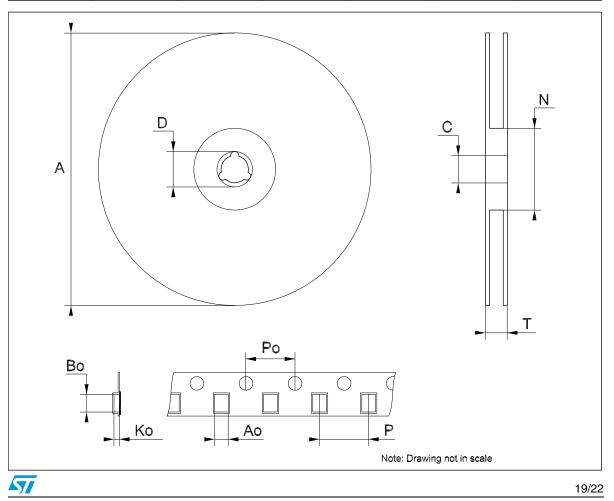


	SOT23-5L mechanical data						
Dim.	mm.			mils.			
Diili.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	0.90		1.45	35.4		57.1	
A1	0.00		0.10	0.0		3.9	
A2	0.90		1.30	35.4		51.2	
b	0.35		0.50	13.7		19.7	
С	0.09		0.20	3.5		7.8	
D	2.80		3.00	110.2		118.1	
E	1.50		1.75	59.0		68.8	
е		0.95			37.4		
Н	2.60		3.00	102.3		118.1	
L	0.10		0.60	3.9		23.6	



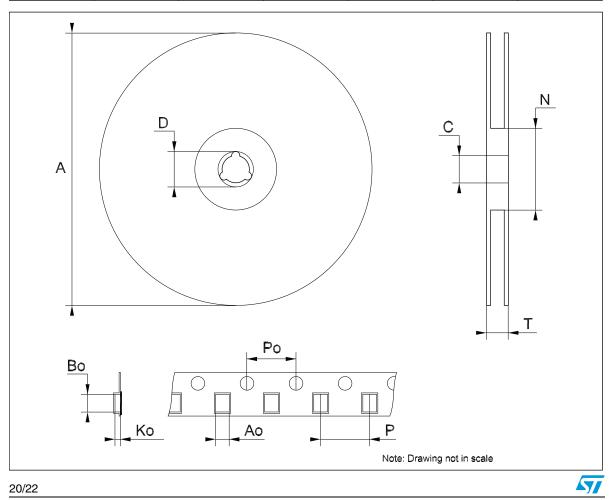
Dim.		mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			180			7.086	
С	12.8	13.0	13.2	0.504	0.512	0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			14.4			0.567	
Ao	3.13	3.23	3.33	0.123	0.127	0.131	
Во	3.07	3.17	3.27	0.120	0.124	0.128	
Ko	1.27	1.37	1.47	0.050	0.054	0.0.58	
Po	3.9	4.0	4.1	0.153	0.157	0.161	
Р	3.9	4.0	4.1	0.153	0.157	0.161	





in. 2.8 0.2	Тур. 13.0	Max. 180 13.2	Min. 0.504	Typ. 0.512	
).2	13.0			0.512	7.086 0.519
).2	13.0	13.2		0.512	0.519
			0 705		
		1	0.795		
50			2.362		
		14.4			0.567
70	4.80	4.90	0.185	0.189	0.193
30	4.40	4.50	0.169	0.173	0.177
70	1.80	1.90	0.067	0.071	0.075
.9	4.0	4.1	0.153	0.157	0.161
	70 30 70	70 4.80 30 4.40 70 1.80 .9 4.0	14.4 70 4.80 30 4.40 4.50 70 1.80 1.90 .9 4.0	14.4 70 4.80 4.90 0.185 30 4.40 4.50 0.169 70 1.80 1.90 0.067 .9 4.0 4.1 0.153	14.4 70 4.80 4.90 0.185 0.189 30 4.40 4.50 0.169 0.173 70 1.80 1.90 0.067 0.071 .9 4.0 4.1 0.153 0.157





9 Revision history

Date	Revision	Changes	
03-Jul-2006	13	Order codes updated and new template.	
13-Nov-2006	14	Add part number LD2980ABU18TR.	
06-Sep-2007	15	Add Table 1 on page 1.	
14-Feb-2008	16	Modified: Table 1 on page 1.	

Table 7.Document revision history



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